

5A, 20V - 200V Schottky Barrier Surface Mount Rectifier

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Guard ring for overvoltage protection
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- Converter

MECHANICAL DATA

- Case: DO-214AB (SMC)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: Indicated by cathode band
- Weight: 0.210g (approximately)

KEY PARAMETERS						
PARAMETER	VALUE	UNIT				
lf	5	А				
V _{RRM}	20 - 200 V					
IFSM	120 A					
Тј мах	150 °C					
Package	DO-214AB (SMC)					
Configuration	Single die					





DO-214AB (SMC)

Cathode ———	\blacksquare	Anode
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PARAMETER SYI		SK	SK	SK	SK	SK	SK	SK	SK	SK	
	SYMBOL	52C	53C	54C	55C	56C	59C	510C	515C	520C	UNIT
Marking code on the device		SK 52C	SK 53C	SK 54C	SK 55C	SK 56C	SK 59C	SK 510C	SK 515C	SK 520C	
Repetitive peak reverse voltage	Vrrm	20	30	40	50	60	90	100	150	200	V
Reverse voltage, total rms value	V _{R(RMS)}	14	21	28	35	42	63	70	105	140	V
Forward current	IF	5					А				
Surge peak forward current, 8.3ms single half sine-wave superimposed on rated load	I _{FSM}	120					А				
Critical rate of rise of off-state voltage	dV/dt	10,000					V/µs				
Junction temperature	TJ	- 55 to +150					°C				
Storage temperature	T _{STG}	- 55 to +150				°C					



THERMAL PERFORMANCE						
PARAMETER	SYMBOL	ТҮР	UNIT			
Junction-to-lead thermal resistance	R _{ejL}	13	°C/W			
Junction-to-ambient thermal resistance	Reja	53	°C/W			
Junction-to-case thermal resistance	Rejc	16	°C/W			

Thermal Performance Note: Units mounted on PCB (16mm x 16mm Cu pad test board)

PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
	SK52C SK53C SK54C			-	0.55	V
Forward voltage ⁽¹⁾	SK55C SK56C	I _F = 5A, T _J = 25°C	VF	-	0.75	V
	SK59C SK510C			-	0.85	V
	SK515C SK520C			-	0.95	V
	SK52C SK53C SK54C SK55C SK56C	TJ = 25°C	IR	-	0.5	mA
Reverse current @ rated V _R ⁽²⁾	SK59C SK510C SK515C SK520C			-	0.3	mA
	SK52C SK53C SK54C		IR	-	20	mA
	SK55C SK56C	T」= 100°C		-	10	mA
	SK59C SK510C SK515C SK520C		IK .	-	-	mA
	SK52C SK53C SK54C		IR	-	-	mA
	SK55C SK56C	T」= 125°C		-	-	mA
	SK59C SK510C SK515C SK520C	ιĸ	-	5	mA	

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION						
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING				
SK5xC	DO-214AB (SMC)	3,000 / Tape & Reel				

Notes:

1. "x" defines voltage from 20V(SK52C) to 200V(SK520C)



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

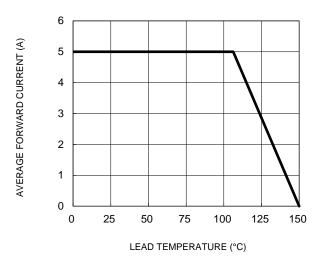
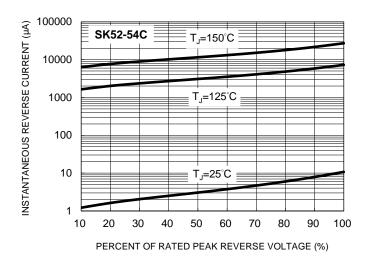
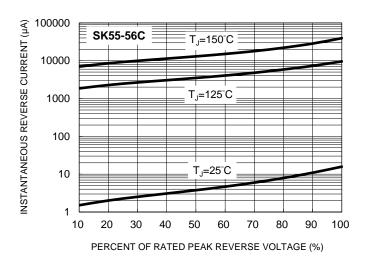


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics

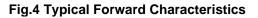






1000 CAPACITANCE (pF) 100 SK52-54C SK55-56C SK59-510C f=1.0MHz SK515-520C Vsig=50mVp-p 10 0.1 10 100 1 **REVERSE VOLTAGE (V)**

Fig.2 Typical Junction Capacitance



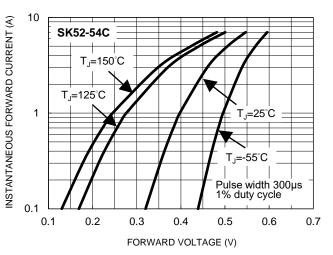
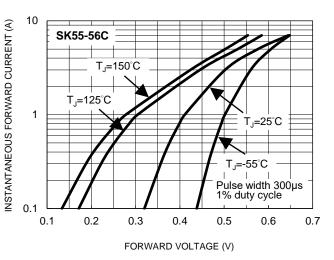


Fig.6 Typical Forward Characteristics





CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

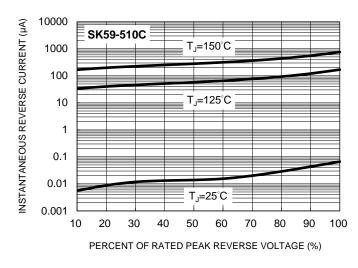


Fig.7 Typical Reverse Characteristics

Fig.9 Typical Reverse Characteristics

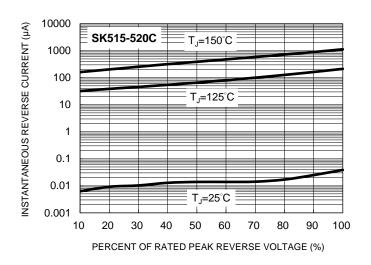
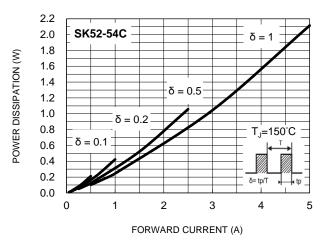


Fig.11 Typical Forward Power Dissipation vs. **Forward Current**



10 INSTANTANEOUS FORWARD CURRENT (A) SK59-510C T_J=150°C T_=125°C 1 T_J=25°C T_J=-55°C Pulse width 300µs 1% duty cycle 0 1 0.3 0.2 0.4 0.5 0.6 0.7 0.8 0.9 1 FORWARD VOLTAGE (V)

Fig.8 Typical Forward Characteristics

Fig.10 Typical Forward Characteristics

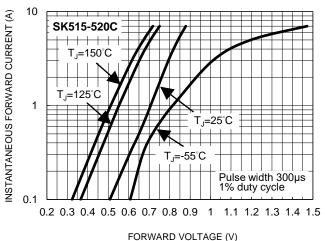
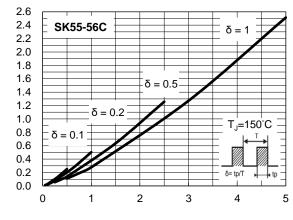


Fig.12 Typical Forward Power Dissipation vs. **Forward Current**



FORWARD CURRENT (A)

POWER DISSIPATION (W)



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

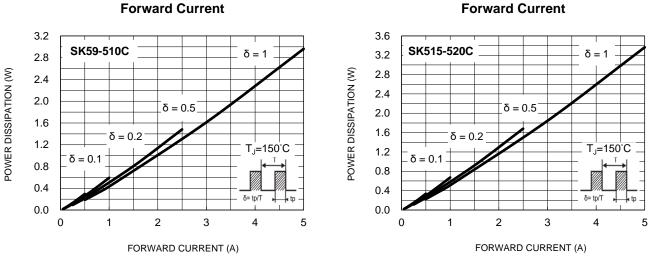
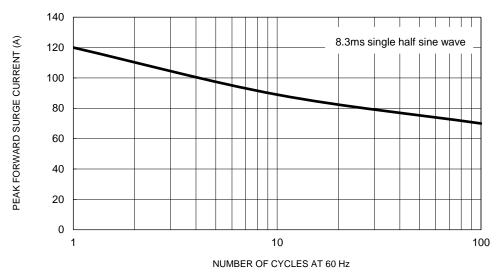
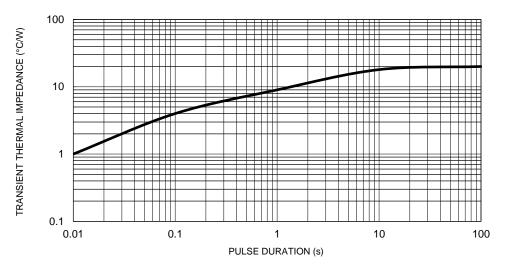


Fig.13 Typical Forward Power Dissipation vs. Fig.14 Typical Forward Power Dissipation vs. **Forward Current**

Fig.15 Maximum Non-Repetitive Forward Surge Current

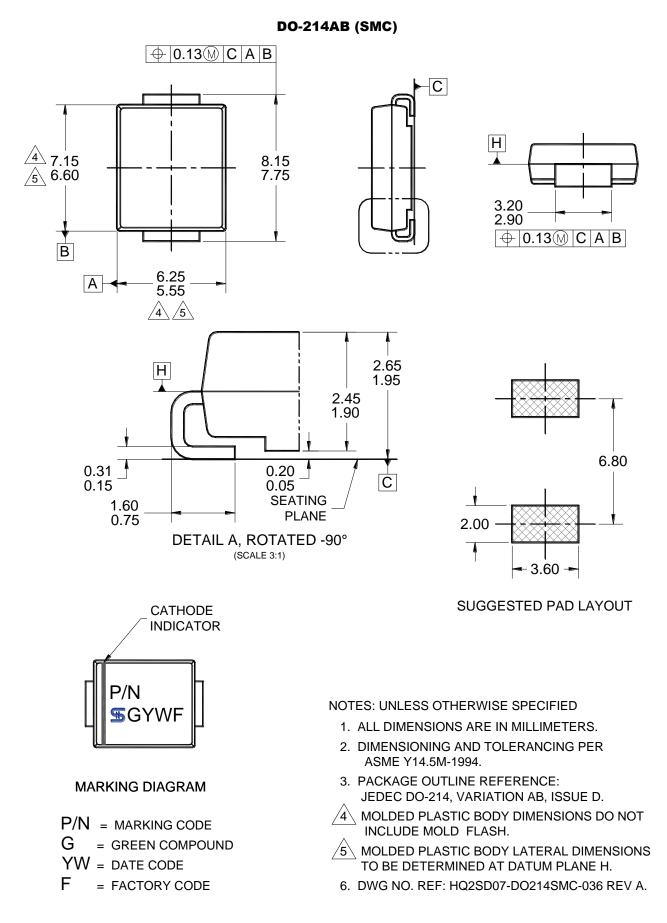








PACKAGE OUTLINE DIMENSIONS





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